Buck Converter -Synchronous 3 MHz, 2 A

The NCV6334B, a family of synchronous buck converters, which is optimized to supply different sub systems of portable applications powered by one cell Li–ion or three cell Alkaline/NiCd/NiMH batteries. The devices are able to deliver up to 2 A on an external adjustable voltage. Operation with 3 MHz switching frequency allows employing small size inductor and capacitors. Input supply voltage feedforward control is employed to deal with wide input voltage range. Synchronous rectification and automatic PWM/PFM power save mode offer improved system efficiency. The NCV6334B is in a space saving, low profile 2.0 x 2.0 x 0.75 mm WDFN–8 package.

Features

- 2.3 V to 5.5 V Input Voltage Range
- External Adjustable Voltage
- Up to 2 A Output Current
- 3 MHz Switching Frequency
- Synchronous Rectification
- Automatic Power Save
- Enable Input
- Power Good Output Option
- Soft Start
- Over Current Protection
- Active Discharge When Disabled
- Thermal Shutdown Protection
- WDFN-8, 2 x 2 mm, 0.5 mm Pitch Package
- Maximum 0.8 mm Height for Super Thin Applications
- This is a Pb–Free Device

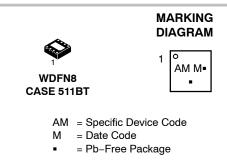
Typical Applications

- Cellular Phones, Smart Phones, and PDAs
- Portable Media Players
- Digital Still Cameras
- Wireless and DSL Modems
- USB Powered Devices
- Point of Load
- Game and Entertainment System



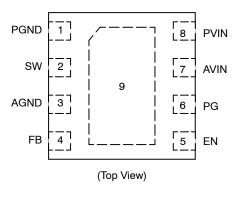
ON Semiconductor®

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(*Note: Microdot may be in either location)





ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 2 of this data sheet.

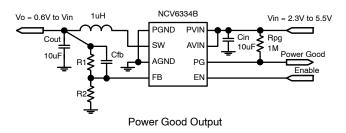


Figure 1. Typical Application Circuits

PIN DESCRIPTION

Pin	Name	Туре	Description
1	PGND	Power Ground	Power Ground for power, analog blocks. Must be connected to the system ground.
2	SW	Power Output	Switch Power pin connects power transistors to one end of the inductor.
3	AGND	Analog Ground	Analog Ground analog and digital blocks. Must be connected to the system ground.
4	FB	Analog Input	Feedback Voltage from the buck converter output. This is the input to the error amplifier. This pin is connected to the resistor divider network between the output and AGND.
5	EN	Digital Input	Enable of the IC. High level at this pin enables the device. Low level at this pin disables the de- vice.
6	PG	Digital Output	PG pin is for NCV6334B with Power Good option. It is open drain output. Low level at this pin indicates the device is not in power good, while high impedance at this pin indicates the device is in power good.
7	AVIN	Analog Input	Analog Supply. This pin is the analog and the digital supply of the device. An optional 1 μ F or larger ceramic capacitor bypasses this input to the ground. This capacitor should be placed as close as possible to this input.
8	PVIN	Power Input	Power Supply Input. This pin is the power supply of the device. A 10 μF or larger ceramic capacitor must bypass this input to the ground. This capacitor should be placed as close a possible to this input.
9	PAD	Exposed Pad	Exposed Pad. Must be soldered to system ground to achieve power dissipation performances. This pin is internally unconnected

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NCV6334BMTAATBG	АМ	WDFN8 (Pb–Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

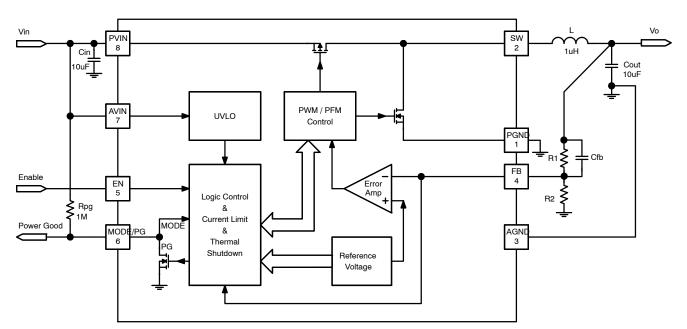


Figure 2. Functional Block Diagram

MAXIMUM RATINGS

		Va	lue	
Rating	Symbol	Min	Max	Unit
Input Supply Voltage to GND	V _{PVIN} , V _{AVIN}	-0.3	7.0	V
Switch Node to GND	V _{SW}	-0.3	7.0	V
EN, PG to GND	V _{EN} , V _{PG}	-0.3	7.0	V
FB to GND	V _{FB}	-0.3	2.5	V
Human Body Model (HBM) ESD Rating (Note 1)	ESD HBM		2000	V
Machine Model (MM) ESD Rating (Note 1)	ESD MM		200	V
Latchup Current (Note 2)	I _{LU}	-100	100	mA
Operating Junction Temperature Range (Note 3)	TJ	-40	125	°C
Operating Ambient Temperature Range	T _A	-40	85	°C
Storage Temperature Range	T _{STG}	-55	150	°C
Thermal Resistance Junction-to-Top Case (Note 4)	$R_{ ext{ heta}JC}$	1	2	°C/W
Thermal Resistance Junction-to-Board (Note 4)	$R_{ heta JB}$	3	30	°C/W
Thermal Resistance Junction-to-Ambient (Note 4)	R _{0JA}	62		°C/W
Power Dissipation (Note 5)	PD	1	.6	W
Moisture Sensitivity Level (Note 6)	MSL		1	-

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. This device series contains ESD protection and passes the following tests: Human Body Model (HBM) ±2.0 kV per JEDEC standard: JESD22–A114.

Machine Model (MM) ±200 V per JEDEC standard: JESD22-A115.

2. Latchup Current per JEDEC standard: JESD78 Class II.

3. The thermal shutdown set to 160°C (typical) avoids potential irreversible damage on the device due to power dissipation.

4. The thermal resistance values are dependent of the PCB heat dissipation. Board used to drive these data was an 80 x 50 mm NCP6334EVB board. It is a multilayer board with 1 once internal power and ground planes and 2–once copper traces on top and bottom of the board. If the copper trances of top and bottom are 1 once too, R_{0JC} = 11°C/W, R_{0JB} = 30°C/W, and R_{0JA} = 72°C/W.

5. The maximum power dissipation (PD) is dependent on input voltage, maximum output current and external components selected.

6. Moisture Sensitivity Level (MSL): 1 per IPC/JEDEC standard: J-STD-020A.

ELECTRICAL CHARACTERISTICS (V_{IN} = 3.6 V, V_{OUT} = 1.8 V, L = 1 μ H, C = 10 μ F, typical values are referenced to T_J = 25°C, Min and Max values are referenced to T_J up to 125°C, unless other noted.)

Symbol	Characteristics	Test Conditions	Min	Тур	Max	Unit
SUPPLY VC	DLTAGE					
V _{IN}	Input Voltage V _{IN} Range	(Note 10)	2.3	-	5.5	V
SUPPLY CL	JRRENT				-	-
Ι _Q	VIN Quiescent Supply Current	EN high, no load, no switching, PFM Mode	-	30	_	μΑ
I _{SD}	V _{IN} Shutdown Current	EN low	-	-	1	μΑ
Ουτρυτ να	OLTAGE					
V _{OUT}	Output Voltage Range	(Note 7)	0.6	-	V _{IN}	V
V_{FB}	FB Voltage	PWM Mode	594	600	606	mV
	FB Voltage in Load Regulation	$\label{eq:VIN} \begin{array}{l} V_{IN} = 3.6 \text{ V}, \text{ I}_{OUT} \text{ from 200 mA to I}_{OUTMAX}, \\ \text{PWM mode (Note 7)} \end{array}$	-	-0.5	-	%/A
	FB Voltage in Line Regulation	I_{OUT} = 200 mA, $V_{\rm IN}$ from MAX (V_{NOM} + 0.5 V, 2.3 V) to 5.5 V, PWM mode (Note 7)	-	0	-	%/V
D _{MAX}	Maximum Duty Cycle	(Note 7)	-	100	-	%
OUTPUT CI	URRENT				-	
I _{OUTMAX}	Output Current Capability	(Note 7)	2.0	-	_	Α
I _{LIM}	Output Peak Current Limit		2.3	2.8	3.3	Α
	MONITOR					
V _{INUV-}	V _{IN} UVLO Falling Threshold		-	-	2.3	V
V _{INHYS}	V _{IN} UVLO Hysteresis		60	-	200	mV
V _{PGL}	Power Good Low Threshold	V _{OUT} falls down to cross the threshold (percentage of FB voltage) (Note 8)	87	90	92	%
V _{PGHYS}	Power Good Hysteresis	V _{OUT} rises up to cross the threshold (percentage of Power Good Low Threshold (V _{PGL}) voltage) (Note 8)	0	3	5	%
Td _{PGH1}	Power Good High Delay in Start Up	From EN rising edge to PG going high. (Note 8)	-	1.15	-	ms
Td_{PGL1}	Power Good Low Delay in Shut Down	From EN falling edge to PG going low. (Notes 7 and 8)	-	8	_	μs
Td _{PGH}			-	5	-	μs
Td _{PGL}	PGL Power Good Low Delay in Regulation From V _{FB} going lower than 90% nominative level to PG going low. (Notes 7 and 8)		-	8	-	μs
VPG_L	Power Good Pin Low Voltage	Voltage at PG pin with 5 mA sink current (Note 8)	-	-	0.3	V
PG_LK	Power Good Pin Leakage Current	3.6 V at PG pin when power good valid (Note 8)	-	-	100	nA

INTEGRATED MOSFETs

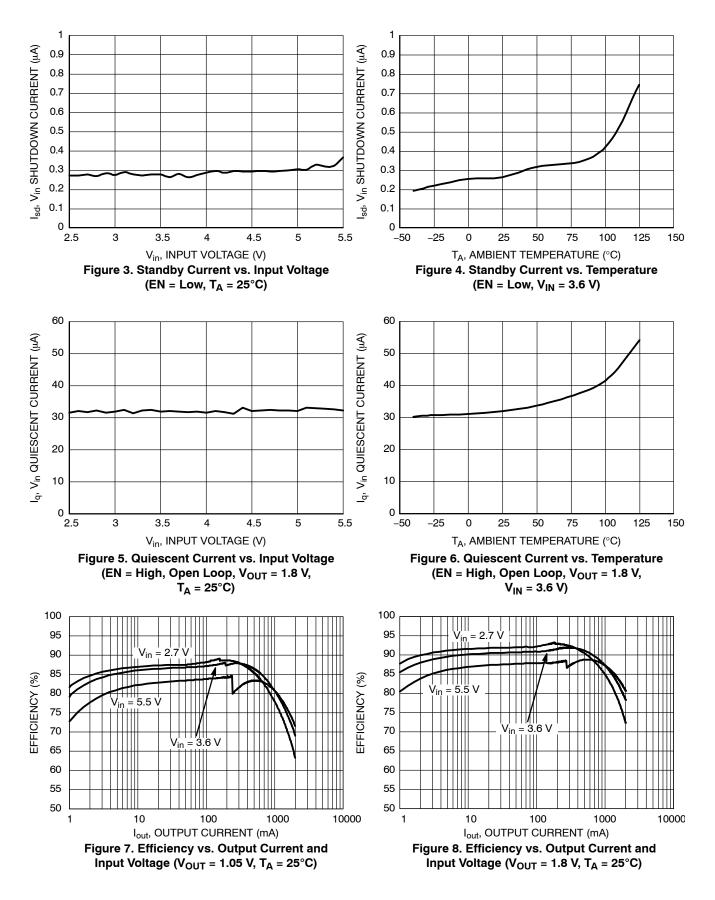
R _{ON_H}	High-Side MOSFET ON Resistance	V _{IN} = 3.6 V (Note 9) V _{IN} = 5 V (Note 9)	-	140 130	200 -	mΩ
R _{ON_L}	Low-Side MOSFET ON Resistance	V _{IN} = 3.6 V (Note 9) V _{IN} = 5 V (Note 9)	-	110 100	140 _	mΩ

Guaranteed by design, not tested in production.
 Power Good function is for NCV6334B devices only.
 Maximum value applies for T_J = 85°C.
 Operation above 5.5 V input voltage for extended periods may affect device reliability.

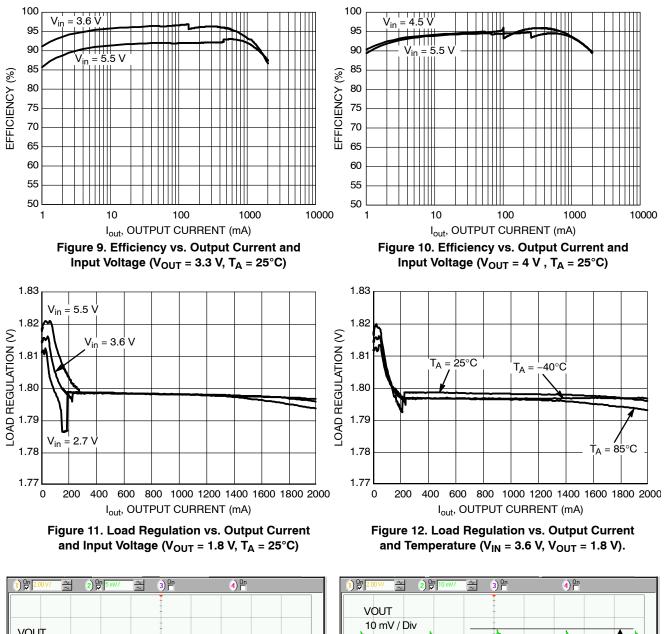
ELECTRICAL CHARACTERISTICS (V_{IN} = 3.6 V, V_{OUT} = 1.8 V, L = 1 μ H, C = 10 μ F, typical values are referenced to T_J = 25°C, Min and Max values are referenced to T_J up to 125°C, unless other noted.)

Symbol	Characteristics	Test Conditions	Min	Тур	Max	Unit
SWITCHING						
F _{SW}	Normal Operation Frequency		2.7	3.0	3.3	MHz
SOFT STAF	it					
T _{SS}	Soft-Start Time	Time from EN to 90% of output voltage target	-	0.4	1	ms
CONTROL	LOGIC		-		-	
V_{EN_H}	EN Input High Voltage		1.1	-	-	V
V _{EN_L}	EN Input Low Voltage		-	-	0.4	V
V _{EN_HYS}	EN Input Hysteresis		-	270	-	mV
I _{EN_BIAS}	EN Input Bias Current			0.1	1	μΑ
OUTPUT A	CTIVE DISCHARGE					
R_DIS	Internal Output Discharge Resistance	from SW to PGND	75	500	700	Ω
THERMAL	SHUTDOWN					
T _{SD}	Thermal Shutdown Threshold		-	160	-	°C
T _{SD HYS}	Thermal Shutdown Hysteresis		-	25	-	°C

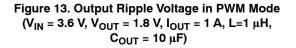
TYPICAL OPERATING CHARACTERESTICS

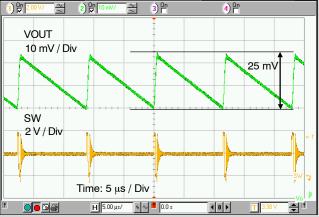


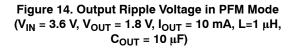
TYPICAL OPERATING CHARACTERESTICS

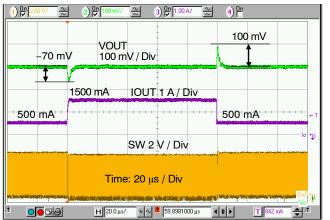












TYPICAL OPERATING CHARACTERESTICS

Figure 15. Load Transient Response (V_{IN} = 3.6 V, V_{OUT} = 1.8 V, I_{OUT} = 500 mA to 1500 mA, L = 1 μ H, C_{OUT} = 10 μ F)

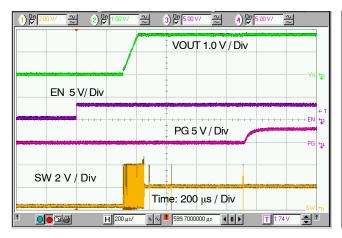


Figure 17. Power Up Sequence and Power Good (V_{IN} = 3.6 V, V_{OUT} = 1.8 V, I_{OUT} = 0 A, L = 1 μ H, C_{OUT} = 10 μ F)

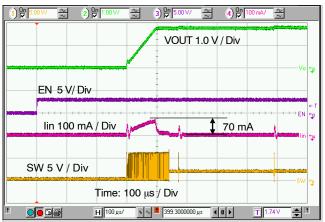


Figure 16. Power Up Sequence and Inrush Current in Input (V_{IN} = 3.6 V, V_{OUT} = 1.8 V, I_{OUT} = 0 A, L = 1 μ H, C_{OUT} = 10 μ F)

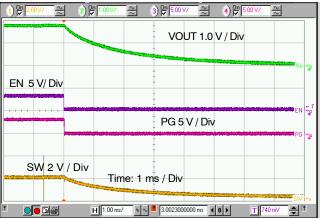


Figure 18. Power Down Sequence and Active Output Discharge (V_{IN} = 3.6 V, V_{OUT} = 1.8 V, I_{OUT} = 0 A, L = 1 μ H, C_{OUT} = 10 μ F)

DETAILED DESCRIPTION

General

The NCV6334B, a family of voltage-mode synchronous buck converters, which is optimized to supply different sub-systems of portable applications powered by one cell Li-ion or three cell Alkaline/NiCd/NiMH batteries. The devices are able to deliver up to 2 A on an external adjustable voltage. Operation with 3 MHz switching frequency allows employing small size inductor and capacitors. Input supply voltage feedforward control is employed to deal with wide input voltage range. Synchronous rectification and automatic PWM/PFM power save mode offer improved system efficiency.

PWM Mode Operation

In medium and heavy load range, the inductor current is continuous and the device operates in PWM mode with fixed switching frequency, which has a typical value of 3 MHz. In this mode, the output voltage is regulated by on-time pulse width modulation of an internal P-MOSFET. An internal N-MOSFET operates as synchronous rectifier and its turn-on signal is complimentary to that of the P-MOSFET.

PFM Mode Operation

In light load range, the inductor current becomes discontinuous and the device automatically operates in PFM mode with an adaptive fixed on time and variable switching frequency. In this mode, the output voltage is regulated by pulse frequency modulation of the internal P–MOSFET, and the switching frequency is almost proportional to the loading current. The internal N–MOSFET operates as synchronous rectifier after each on pulse of the P–MOSFET with a very small negative current limit. When the load increases and the inductor current becomes continuous, the controller automatically turns back to the fixed–frequency PWM mode operation.

Undervoltage Lockout

The input voltage VIN must reach or exceed 2.4 V (typical) before the NCV6334B enables the converter output to begin the start up sequence. The UVLO threshold hysteresis is typically 100 mV.

Enable

The NCV6334B has an enable logic input pin EN. A high level (above 1.1 V) on this pin enables the device to active mode. A low level (below 0.4 V) on this pin disables the device and makes the device in shutdown mode. There is an internal filter with 5 μ s time constant. The EN pin is pulled down by an internal 10 nA sink current source. In most of applications, the EN signal can be programmed independently to VIN power sequence.

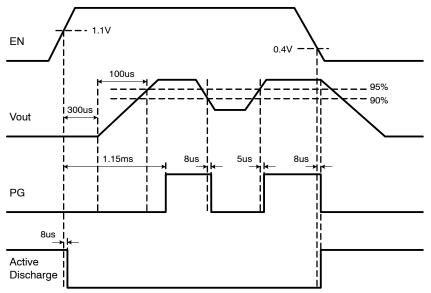


Figure 19. Power Good and Active Discharge Timing Diagram

Power Good Output

For NCV6334B with a power good output, the device monitors the output voltage and provides a power good output signal at the PG pin. This pin is an open-drain output pin. To indicate the output of the converter is established, a power good signal is available. The power good signal is low when EN is high but the output voltage has not been established. Once the output voltage of the converter drops out below 90% of its regulation during operation, the power good signal is pulled low and indicates a power failure. A 5% hysteresis is required on power good comparator before signal going high again.

Soft-Start

A soft start limits inrush current when the converter is enabled. After a minimum 300 μ s delay time following the enable signal, the output voltage starts to ramp up in 100 μ s (for external adjustable voltage devices) or with a typical 10 V/ms slew rate (for fixed voltage devices).

Active Output Discharge

An output discharge operation is active in when EN is low. A discharge resistor (500 Ω typical) is enabled in this condition to discharge the output capacitor through SW pin.

Cycle-by-Cycle Current Limitation

The NCV6334B protects the device from over current with a fixed-value cycle-by-cycle current limitation. The typical peak current limit ILMT is 2.8 A. If inductor current exceeds the current limit threshold, the P-MOSFET will be turned off cycle-by-cycle. The maximum output current can be calculated by

$$\mathbf{I}_{MAX} = \mathbf{I}_{LMT} - \frac{\mathbf{V}_{OUT} \cdot \left(\mathbf{V}_{IN} - \mathbf{V}_{OUT}\right)}{2 \cdot \mathbf{V}_{IN} \cdot f_{SW} \cdot \mathbf{L}} \qquad (\text{eq. 1})$$

where VIN is input supply voltage, VOUT is output voltage, L is inductance of the filter inductor, and f_{SW} is 3 MHz normal switching frequency.

Thermal Shutdown

The NCV6334B has a thermal shutdown protection to protect the device from overheating when the die temperature exceeds 160°C. After the thermal protection is triggered, the fault state can be ended by re–applying VIN and/or EN when the temperature drops down below 125°C.

APPLICATION INFORMATION

Output Filter Design Considerations

The output filter introduces a double pole in the system at a frequency of

$$f_{\rm LC} = \frac{1}{2 \cdot \pi \cdot \sqrt{L \cdot C}} \qquad (eq. 2)$$

The internal compensation network design of the NCV6334B is optimized for the typical output filter comprised of a 1.0 μ H inductor and a 10 μ F ceramic output capacitor, which has a double pole frequency at about 50 kHz. Other possible output filter combinations may have a double pole around 50 kHz to have optimum operation with the typical feedback network. Normal selection range of the inductor is from 0.47 μ H to 4.7 μ H, and normal selection range of the output capacitor is from 4.7 μ F to 22 μ F.

Inductor Selection

The inductance of the inductor is determined by given peak-to-peak ripple current IL_PP of approximately 20%

to 50% of the maximum output current IOUT_MAX for a trade-off between transient response and output ripple. The inductance corresponding to the given current ripple is

$$L = \frac{\left(V_{IN} - V_{OUT}\right) \cdot V_{OUT}}{V_{IN} \cdot f_{SW} \cdot I_{L_{PP}}}$$
(eq. 3)

The selected inductor must have high enough saturation current rating to be higher than the maximum peak current that is

$$I_{L_MAX} = I_{OUT_MAX} + \frac{I_{L_PP}}{2}$$
 (eq. 4)

The inductor also needs to have high enough current rating based on temperature rise concern. Low DCR is good for efficiency improvement and temperature rise reduction. Table 1 shows some recommended inductors for high power applications and Table 2 shows some recommended inductors for low power applications.

Table 1. LIST OF RECOMMENDED INDUCTORS FOR HIGH POWER APPLICATIONS
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Manufacturer	Part Number	Case Size (mm)	L (µH)	Rated Current (mA) (Inductance Drop)	Structure
MURATA	LQH44PN2R2MP0	4.0 x 4.0 x 1.8	2.2	2500 (-30%)	Wire Wound
MURATA	LQH44PN1R0NP0	4.0 x 4.0 x 1.8	1.0	2950 (-30%)	Wire Wound
MURATA	LQH32PNR47NNP0	3.0 x 2.5 x 1.7	0.47	3400 (-30%)	Wire Wound

Table 2. LIST OF RECOMMENDED INDUCTORS FOR LOW POWER APPLICATIONS

Manufacturer	Part Number	Case Size (mm)	L (µH)	Rated Current (mA) (Inductance Drop)	Structure
MURATA	LQH44PN2R2MJ0	4.0 x 4.0 x 1.1	2.2	1320 (–30%)	Wire Wound
MURATA	LQH44PN1R0NJ0	4.0 x 4.0 x 1.1	1.0	2000 (-30%)	Wire Wound
TDK	VLS201612ET-2R2	2.0 x 1.6 x 1.2	2.2	1150 (–30%)	Wire Wound
ТДК	VLS201612ET-1R0	2.0 x 1.6 x 1.2	1.0	1650 (–30%)	Wire Wound

Output Capacitor Selection

The output capacitor selection is determined by output voltage ripple and load transient response requirement. For a given peak-to-peak ripple current IL_PP in the inductor of the output filter, the output voltage ripple across the output capacitor is the sum of three ripple components as below.

$$V_{OUT_PP} \approx V_{OUT_PP(C)} + V_{OUT_PP(ESR)} + V_{OUT_PP(ESL)} \label{eq:Vout_PP} \end{tabular}$$
 (eq. 5)

where VOUT_PP(C) is a ripple component by an equivalent total capacitance of the output capacitors, VOUT_PP(ESR) is a ripple component by an equivalent ESR of the output capacitors, and VOUT_PP(ESL) is a ripple component by an equivalent ESL of the output capacitors. In PWM

operation mode, the three ripple components can be obtained by

$$V_{OUT_PP(C)} = \frac{I_{L_PP}}{8 \cdot C \cdot f_{SW}}$$
(eq. 6)

$$V_{OUT_PP(ESR)} = I_{L_PP} \cdot ESR$$
 (eq. 7)

$$V_{OUT_PP(ESL)} = \frac{ESL}{ESL + L} \cdot V_{IN}$$
 (eq. 8)

and the peak-to-peak ripple current is

$$\mathbf{I}_{\mathrm{L}_{\mathrm{PP}}} = \frac{\left(\mathbf{V}_{\mathrm{IN}} - \mathbf{V}_{\mathrm{OUT}}\right) \cdot \mathbf{V}_{\mathrm{OUT}}}{\mathbf{V}_{\mathrm{IN}} \cdot f_{\mathrm{SW}} \cdot \mathbf{L}} \tag{eq. 9}$$

In applications with all ceramic output capacitors, the main ripple component of the output ripple is VOUT_PP(C). So that the minimum output capacitance can be calculated regarding to a given output ripple requirement VOUT PP in PWM operation mode.

$$C_{MIN} = \frac{I_{L_PP}}{8 \cdot V_{OUT PP} \cdot f_{SW}}$$
 (eq. 10)

Input Capacitor Selection

One of the input capacitor selection guides is the input voltage ripple requirement. To minimize the input voltage ripple and get better decoupling in the input power supply rail, ceramic capacitor is recommended due to low ESR and ESL. The minimum input capacitance regarding to the input ripple voltage VIN_PP is

$$\mathbf{C}_{\mathsf{IN}_\mathsf{MIN}} = \frac{\mathbf{I}_{\mathsf{OUT}_\mathsf{MAX}} \cdot (\mathsf{D} - \mathsf{D}^2)}{\mathbf{V}_{\mathsf{IN}_\mathsf{PP}} \cdot f_{\mathsf{SW}}} \qquad (\mathsf{eq.~11})$$

where

$$D = \frac{V_{OUT}}{V_{IN}}$$
 (eq. 12)

In addition, the input capacitor needs to be able to absorb the input current, which has a RMS value of

$$I_{\text{IN}_{\text{RMS}}} = I_{\text{OUT}_{\text{MAX}}} \cdot \sqrt{D - D^2}$$
 (eq. 13)

The input capacitor also needs to be sufficient to protect the device from over voltage spike, and normally at least a $4.7 \,\mu\text{F}$ capacitor is required. The input capacitor should be located as close as possible to the IC on PCB.

Manufacturer	Part Number	Case Size	Height Max (mm)	C (μF)	Rated Voltage (V)	Structure
MURATA	GRM21BR60J226ME39, X5R	0805	1.4	22	6.3	MLCC
TDK	C2012X5R0J226M, X5R	0805	1.25	22	6.3	MLCC
MURATA	GRM21BR61A106KE19, X5R	0805	1.35	10	10	MLCC
TDK	C2012X5R1A106M, X5R	0805	1.25	10	10	MLCC
MURATA	GRM188R60J106ME47, X5R	0603	0.9	10	6.3	MLCC
TDK	C1608X5R0J106M, X5R	0603	0.8	10	6.3	MLCC
MURATA	GRM188R60J475KE19, X5R	0603	0.87	4.7	6.3	MLCC

Table 3. LIST OF RECOMMENDED INPUT CAPACITORS AND OUTPUT CAPACITORS

Design of Feedback Network

For NCV6334B devices with an external adjustable output voltage, the output voltage is programmed by an external resistor divider connected from V_{OUT} to FB and then to AGND, as shown in the typical application schematic Figure 1(a). The programmed output voltage is

$$V_{OUT} = V_{FB} \cdot \left(1 + \frac{R_1}{R_2}\right) \qquad (eq. 14)$$

where V_{FB} is equal to the internal reference voltage 0.6 V, R1 is the resistance from V_{OUT} to FB, which has a normal value range from 50 k Ω to 1 M Ω and a typical value of 220 k Ω for applications with the typical output filter. R2 is the resistance from FB to AGND, which is used to program the output voltage according to equation (14) once the value of R1 has been selected. A capacitor Cfb needs to be employed between the V_{OUT} and FB in order to provide feedforward function to achieve optimum transient response. Normal value range of Cfb is from 0 to 100 pF, and a typical value is 15 pF for applications with the typical output filter and R1 = 220 k Ω .

Table 4 provides reference values of R1 and Cfb in case of different output filter combinations. The final design may need to be fine tuned regarding to application specifications.

R1 (kΩ)		L (µH)					
Cfb (pF)		0.47	0.68	1	2.2	3.3	4.7
С (µF)	4.7	220	220	220	220	330	330
		3	5	8	15	15	22
	10	220	220	220	220	330	330
		8	10	15	27	27	39
	22	220	220	220	220	330	330
		15	22	27	39	47	56

LAYOUT CONSIDERATIONS

Electrical Layout Considerations

Good electrical layout is a key to make sure proper operation, high efficiency, and noise reduction. Electrical layout guidelines are:

- Use wide and short traces for power paths (such as PVIN, VOUT, SW, and PGND) to reduce parasitic inductance and high–frequency loop area. It is also good for efficiency improvement.
- The device should be well decoupled by input capacitor and input loop area should be as small as possible to reduce parasitic inductance, input voltage spike, and noise emission.
- SW node should be a large copper pour, but compact because it is also a noise source.
- It would be good to have separated ground planes for PGND and AGND and connect the two planes at one point. Directly connect AGND pin to the exposed pad and then connect to AGND ground plane through vias. Try best to avoid overlap of input ground loop and output ground loop to prevent noise impact on output regulation.

• Arrange a "quiet" path for output voltage sense and feedback network, and make it surrounded by a ground plane.

Thermal Layout Considerations

Good thermal layout helps high power dissipation from a small package with reduced temperature rise. Thermal layout guidelines are:

- The exposed pad must be well soldered on the board.
- A four or more layers PCB board with solid ground planes is preferred for better heat dissipation.
- More free vias are welcome to be around IC and/or underneath the exposed pad to connect the inner ground layers to reduce thermal impedance.
- Use large area copper especially in top layer to help thermal conduction and radiation.
- Do not put the inductor to be too close to the IC, thus the heat sources are distributed.

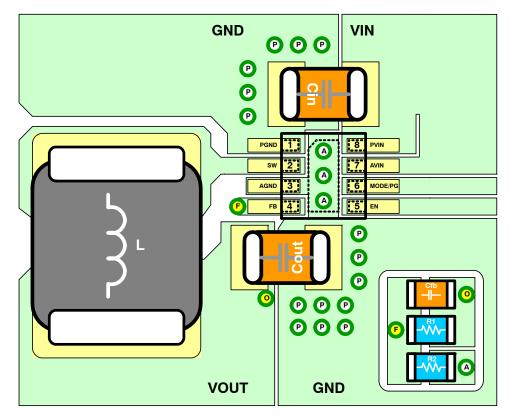
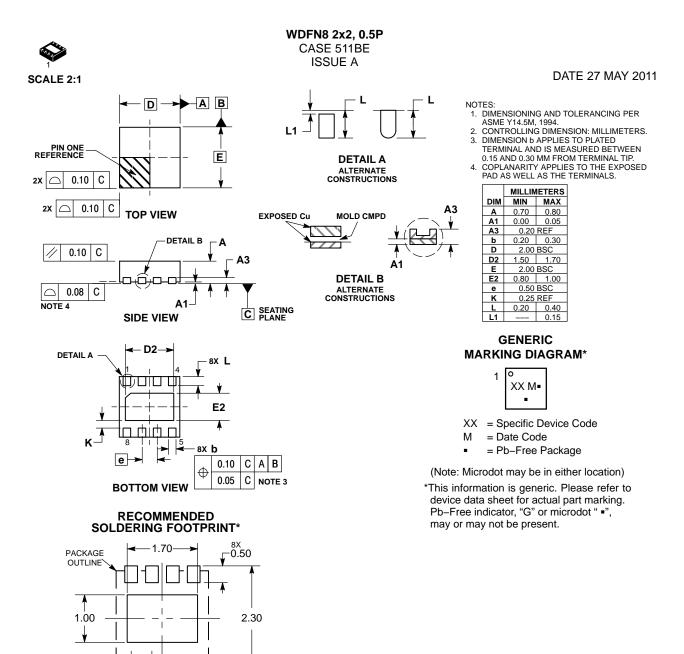


Figure 20. Recommended PCB Layout for Application Boards

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 DESCRIPTION:
 WDFN8, 2X2, 0.5P
 PAGE 1 OF 1

^{8X} 0.30

DIMENSIONS: MILLIMETERS

*For additional information on our Pb–Free strategy and soldering details, please download the **onsemi** Soldering and Mounting

Techniques Reference Manual, SOLDERRM/D.

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0.50→ PITCH

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